Form PTO 1449 (Modified)	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY DOCKET NO. 291682US2RD PCT	SERIAL NO. 10/581,090 New U.S. PCT Application Based on PCTJP06/305070
LIST OF REFERENCES CITED BY APPLICANT		APPLICANT Ryoichi OHARA, et al.	
		FILING DATE Herewith	GROUP

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
/DR/	AA	2005-142888	06/30/05	EBUCHI et al.			
/DR/	AB	6 384 697	05/07/02	RUBY			
	AG						
	AD						
	AF						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES	TRANSLATION NO
	AO					
	AP					
	AO					
	AR					
	AS					
	AT					
	AU					
	AV					

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)

/DR/	AW	LAKIN, K. M. et al., " 1.0-GHz thin-film bulk acoustic wave resonators on GaAs", Appl. Phys. Letter, Vol. 43, No. 8, Pages 750 - 751, 1983.
	AX	
	AY	
	AZ	

☐ Additional References sheet(s) attached

Examiner /Derek Rosenau/ Date Considered 06/02/2008

*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

New U.S. PCT Application Based on PCT/JP06/305070
Ryoichi OHARA, et al.
Docket No. 291682 US

STATEMENT OF RELEVANCY

1) References have been cited in the International Search Report. A copy of these references is being submitted herewith.

2) References have been cited in the corresponding Search Report. A copy of these references is being submitted herewith.

3) References AB & AW are discussed in the specification. A copy of these references is being submitted herewith.

4) References are additional prior art known to Applicant. A copy of these references is being submitted herewith.

AB: *6,384,697*

Technologies of FBAR using a bottom electrode which has edges extending beyond each boundary of cavity are disclosed.

AW: *LAKIN, K. M. et al., " 1.0-GHz thin-film bulk acoustic wave resonators on GaAs", Appl. Phys. Letter, Vol. 43, No. 8, Pages 750 - 751, 1983.*

Technologies of FBAR using a bottom electrode which has edges extending beyond each boundary of cavity are disclosed.

	Docket No.: 291682US2RD PCT	Serial No.: New Application
	Inventor: Ryoichi OHARA, et al.	
LIST OF RELATED CASES CITED BY APPLICANT UNDER 37 CFR 1.56	Filing Date: Herewith	Group:

LIST OF RELATED CASES

Examiner Initial	Docket No.	Serial or Patent Number	Filing or Issue Date	Patent App. Publication No.	Inventor or Applicant
/DR/	256032US2	10/890,989	07/15/04	2005-142888	EBUCHI, et al.
/DR/	287666US2RD	11/376,266	03/16/06		YANASE, et al.

Examiner /Derek Rosenau/ Date Considered 06/02/2008

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